

## Standard Recovery Diodes, (Stud Version), 400 A



DO-9 (DO-205AB)

### FEATURES

- Wide current range
- High voltage ratings up to 2400 V
- High surge current capabilities
- Stud cathode and stud anode version
- Standard JEDEC® types
- Compression bonded encapsulations
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS  
COMPLIANT**

### PRIMARY CHARACTERISTICS

$I_{F(AV)}$	400 A
Package	DO-9 (DO-205AB)
Circuit configuration	Single

### TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

### MAJOR RATINGS AND CHARACTERISTICS

PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{F(AV)}$		480	A
	$T_C$	120	°C
$I_{F(RMS)}$		630	A
$I_{FSM}$	50 Hz	8250	
	60 Hz	8640	
$I^2t$	50 Hz	340	kA <sup>2</sup> s
	60 Hz	311	
$V_{RRM}$	Range	1600 to 2400	V
$T_J$		-40 to +190	°C

### ELECTRICAL SPECIFICATIONS

#### VOLTAGE RATINGS

TYPE NUMBER	VOLTAGE CODE	$V_{RRM}$ , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	$V_{RSM}$ , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$I_{RRM}$ MAXIMUM AT $T_J = T_J$ MAXIMUM mA
VS-SD400N/R	16	1600	1700	15
	20	2000	2100	
	24	2400	2500	



FORWARD CONDUCTION					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current at case temperature	$I_{F(AV)}$	180° conduction, half sine wave		400	A
				120	°C
				480	A
				100	°C
Maximum RMS forward current	$I_{F(RMS)}$	DC at 110 °C case temperature		630	A
Maximum peak, one-cycle forward, non-repetitive surge current	$I_{FSM}$	t = 10 ms	No voltage reappplied	8250	
		t = 8.3 ms	No voltage reappplied	8640	
		t = 10 ms	100 % $V_{RRM}$ reappplied	6940	
		t = 8.3 ms	100 % $V_{RRM}$ reappplied	7270	
Maximum $I^2t$ for fusing	$I^2t$	t = 10 ms	No voltage reappplied	340	kA <sup>2</sup> s
		t = 8.3 ms	No voltage reappplied	311	
		t = 10 ms	100 % $V_{RRM}$ reappplied	241	
		t = 8.3 ms	100 % $V_{RRM}$ reappplied	220	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 to 10 ms, no voltage reappplied		3400	kA <sup>2</sup> √s
Low level value of threshold voltage	$V_{F(TO)1}$	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$ , $T_J = T_J$ maximum		0.80	V
High level value of threshold voltage	$V_{F(TO)2}$	$(I > \pi \times I_{F(AV)})$ , $T_J = T_J$ maximum		0.85	
Low level value of forward slope resistance	$r_{f1}$	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$ , $T_J = T_J$ maximum		0.55	mW
High level value of forward slope resistance	$r_{f2}$	$(I > \pi \times I_{F(AV)})$ , $T_J = T_J$ maximum		0.51	
Maximum forward voltage drop	$V_{FM}$	$I_{pk} = 1500$ A, $T_J = T_J$ maximum, $t_p = 10$ ms sinusoidal wave		1.62	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction operating temperature range	$T_J$			-40 to +190	°C
Maximum storage temperature range	$T_{Stg}$			-55 to +200	
Maximum thermal resistance, junction to case	$R_{thJC}$	DC operation		0.11	K/W
Maximum thermal resistance, case to heatsink	$R_{thCS}$	Mounting surface, smooth, flat and greased		0.04	
Maximum allowed mounting torque ± 10 %		Not-lubricated threads		27	Nm
Approximate weight				250	g
Case style		See dimensions (link at the end of datasheet)		DO-9 (DO-205AB)	

$\Delta R_{thJC}$ CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.020	0.013	$T_J = T_J$ maximum	K/W
120°	0.023	0.023		
90°	0.029	0.031		
60°	0.042	0.044		
30°	0.073	0.074		

**Note**

- The table above shows the increment of thermal resistance  $R_{thJC}$  when devices operate at different conduction angles than DC

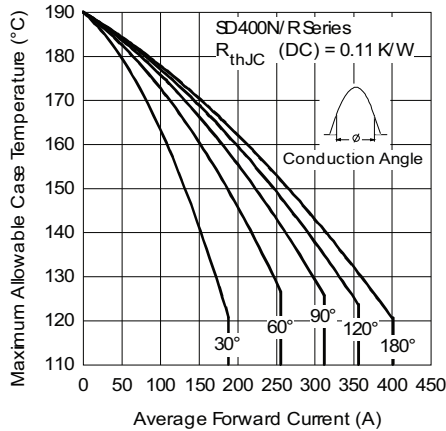


Fig. 1 - Current Ratings Characteristics

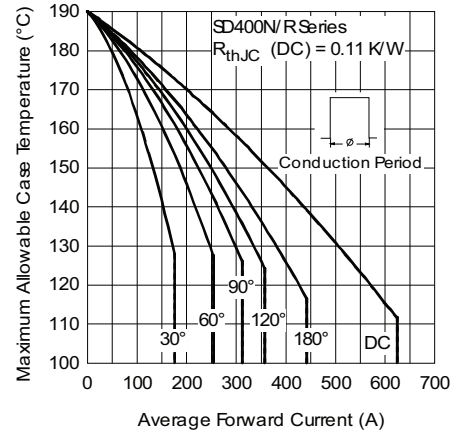


Fig. 2 - Current Ratings Characteristics

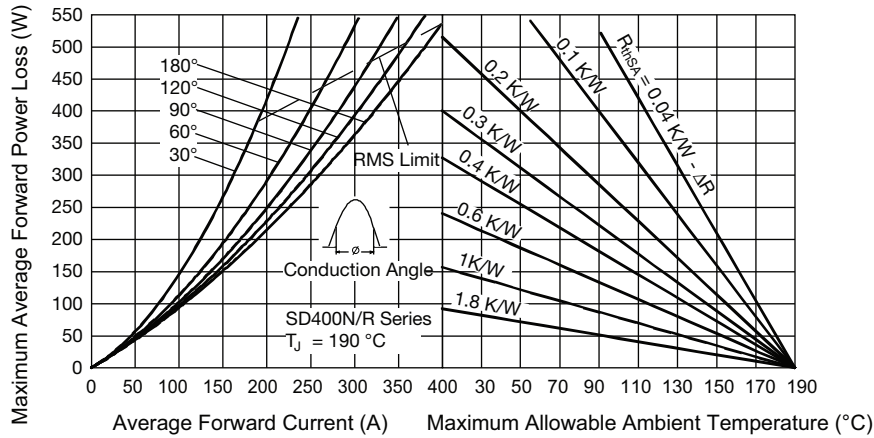


Fig. 3 - Forward Power Loss Characteristics

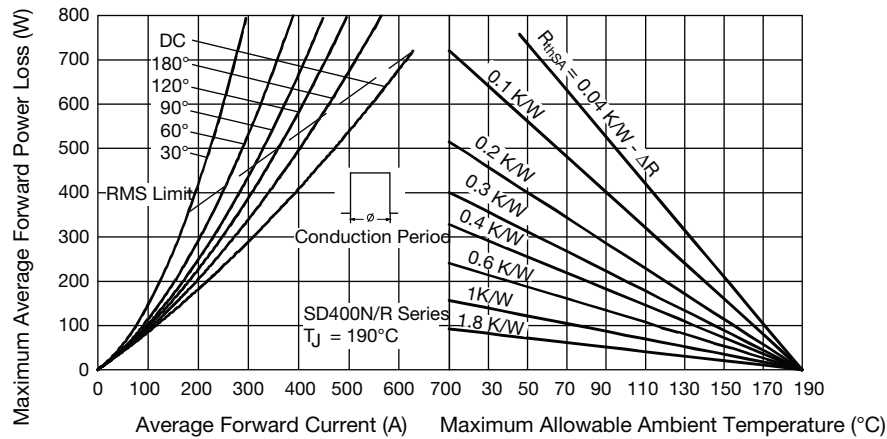


Fig. 4 - Forward Power Loss Characteristics

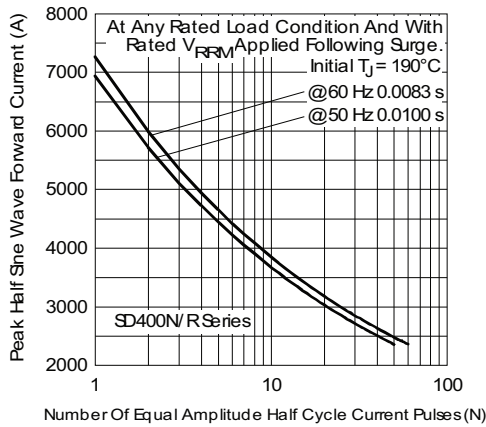


Fig. 5 - Maximum Non-Repetitive Surge Current

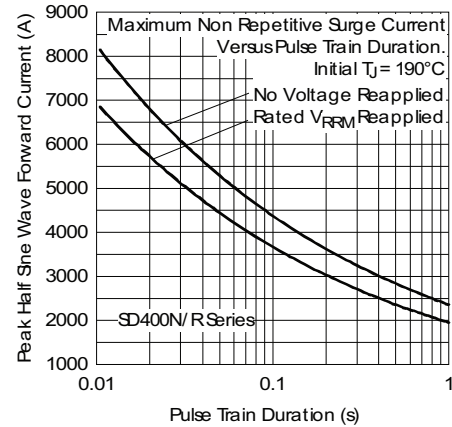


Fig. 6 - Maximum Non-Repetitive Surge Current

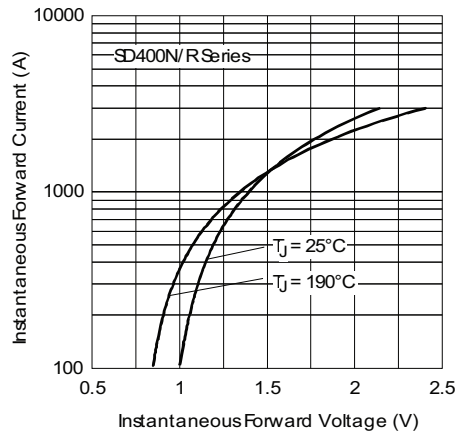


Fig. 7 - Forward Voltage Drop Characteristics

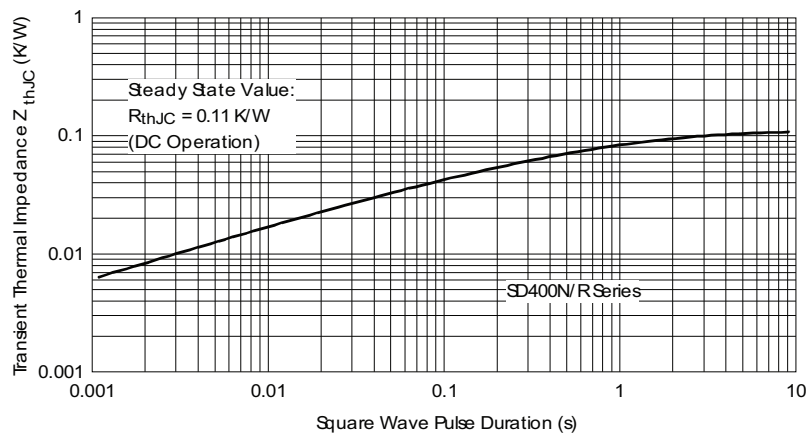
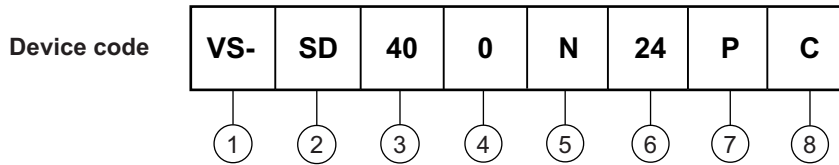


Fig. 8 - Thermal Impedance  $Z_{thJC}$  Characteristic



## ORDERING INFORMATION TABLE

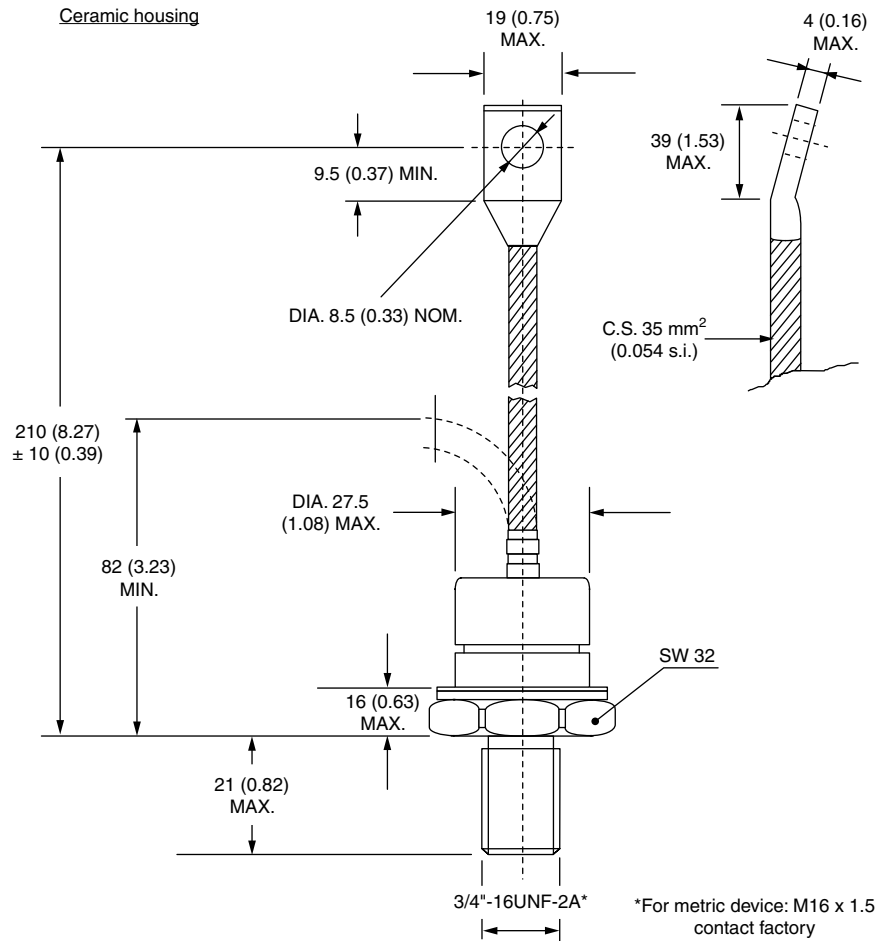


- 1** - Vishay Semiconductors product
- 2** - Diode
- 3** - Essential part number
- 4** - 0 = standard recovery
- 5** -
  - N = stud normal polarity (cathode to stud)
  - R = stud reverse polarity (anode to stud)
- 6** - Voltage code x 100 =  $V_{RRM}$  (see Voltage Ratings table)
- 7** - P = stud base DO-9 (DO-205AB) 3/4" 16UNF-2A
- 8** - C = ceramic housing

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95301">www.vishay.com/doc?95301</a>

## DO-205AB (DO-9)

**DIMENSIONS** in millimeters (inches)





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